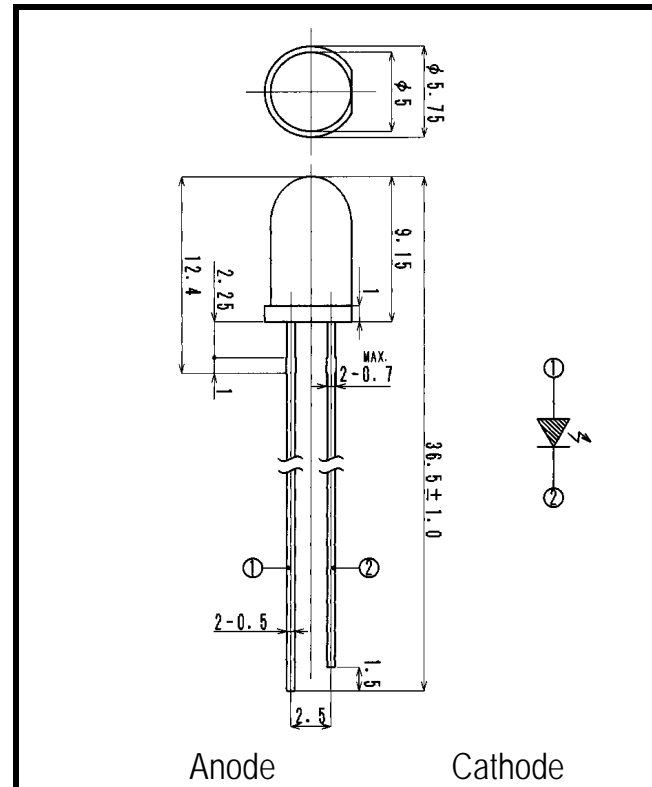
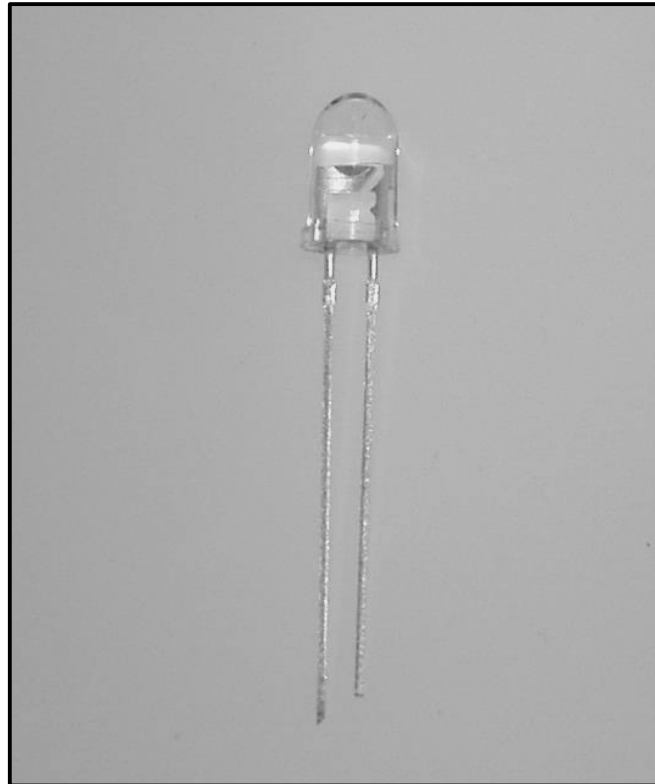


VSF665N5-J

Visible Light Emitting Diode



Anode Cathode
Dimensions (Unit:mm)

2. ELECTRICAL & OPTICAL CHARACTERISTICS (Ta=25)

ITEM	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=20mA	5.0	6.5		mW
Luminous Intensity	Iv	IF=20mA	1200	3000		mcd
Forward Voltage	VF	IF=20mA		1.8	2.2	V
Reverse Current	IR	VR=5V			100	μA
Peak Wavelength	p	IF=20mA		660		nm
Spectral Line Half Width		IF=20mA		25		nm
Half Intensity Beam Angle		IF=20mA		±7		deg.
Rise Time	Tr	IFP=20mA		30		nS
Fall Time	Tf	IFP=20mA		30		nS
Junction Capacitance	Cj	1MHz, V=0V		20		pF
Temp. Coefficient of Iv	I/T	IF=10mA		-0.5		%/
Temp. Coefficient of VF	V/T	IF=10mA		-1.5		mV/

- FEATURES**
- High Output Power
 - High Luminous Intensity
 - Narrow Beam Angle
 - High Reliability
- APPLICATIONS**
- Optical Sensor
 - Bar-code Reader
 - Edge Sensing (Coin Dispenser)
 - Indicators

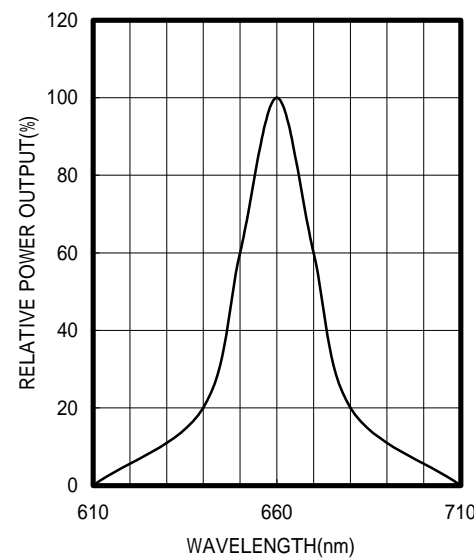
1. ABSOLUTE MAXIMUM RATINGS (Ta=25)

ITEM	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	50	mA
Forward Current (Pulse)*1	IFP	0.5	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	120	mW
Operating Temp.	Topr	-20 TO 80	
Storage Temp.	Tstg	-30 TO 100	
Junction Temp.	Tj	100	
Lead Soldering Temp.*2	Tls	260	

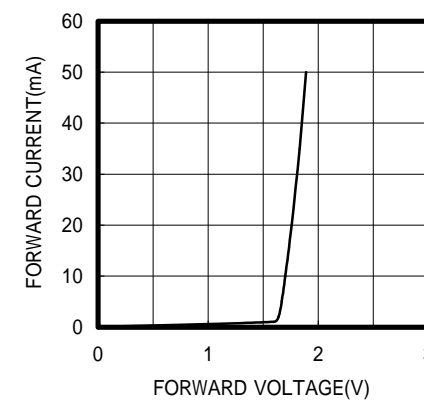
*1:Tw=10uS,T=10mS

*2:Time 3 Sec max,Position:Up to 2mm from the body

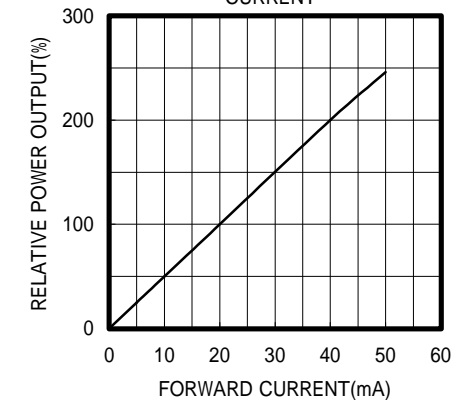
SPECTRAL OUTPUT



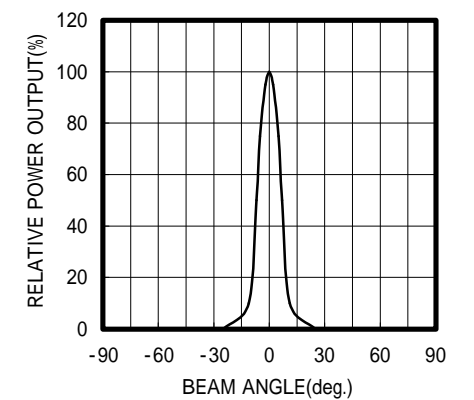
FORWARD I-V CHARACTERISTICS



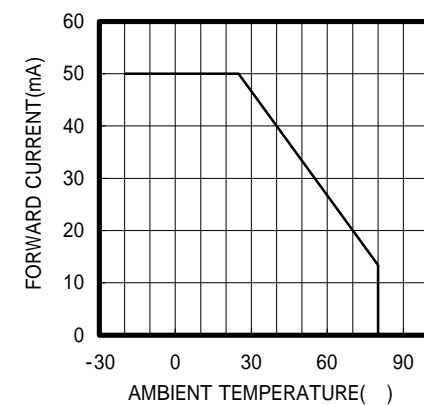
RELATIVE POWER vs FORWARD CURRENT



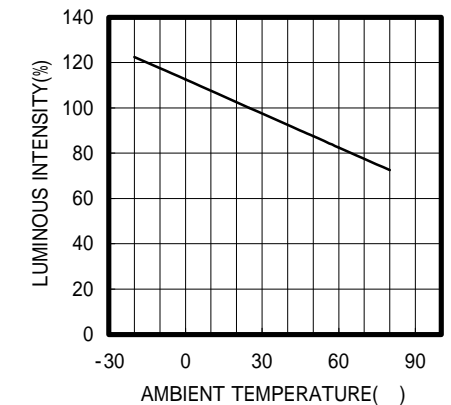
RADIATION PATTERN



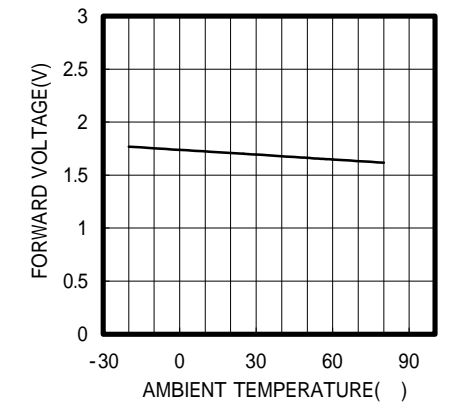
THERMAL DERATING CURVE



LUMINOUS INTENSITY vs TEMPERATURE
IF=10mA



FORWARD VOLTAGE vs TEMPERATURE
IF=10mA



OPTRANS

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